



SOD-523 Plastic-Encapsulate Diodes

1N4148WT FAST SWITCHING DIODES

FEATURES

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance

SOD-523



MARKING: T4

Maximum Ratings and Electrical Characteristics, Single Diode @T_A=25°C

Parameter	Symbol	Limits		Unit	
Non-Repetitive Peak reverse voltage	V _{RM}	100		V	
Peak Repetitive Peak reverse voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RWM}	75		V	
DC Blocking Voltage	V _R				
RMS Reverse Voltage	V _{R(RMS)}	53		V	
Forward Continuous Current	I _{FM}	250		mA	
Average Rectified Output Current	I _O	125		mA	
Peak forward surge current @=1.0μs @=1.0s	I _{FSM}	2.0 1.0		A	
Power Dissipation	P _d	150		mW	
Thermal Resistance Junction to Ambient	R _{θJA}	625		K/W	
Junction temperature	T _j	125		°C	
Storage temperature	T _{STG}	-65~+150		°C	

Electrical Ratings @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{F1}			0.715	V	I _F =1mA
	V _{F2}			0.855	V	I _F =10mA
	V _{F3}			1.0	V	I _F =50mA
	V _{F4}			1.25	V	I _F =150mA
Reverse current	I _{R1}			1	μA	V _R =75V
	I _{R2}			25	nA	V _R =20V
Capacitance between terminals	C _T			2	pF	V _R =0V,f=1MHz
Reverse Recovery Time	t _{rr}			4	ns	I _F =I _R =10mA I _{rr} =0.1XI _R ,R _L =100Ω

Typical Characteristics

1N4148WT

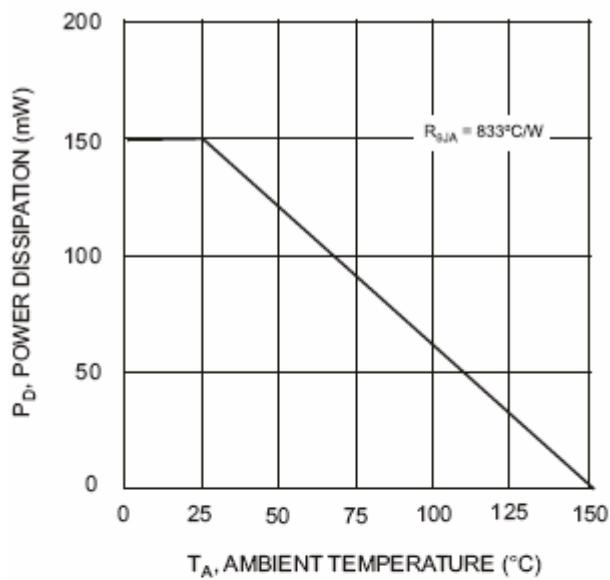


Fig. 1 Derating Curve

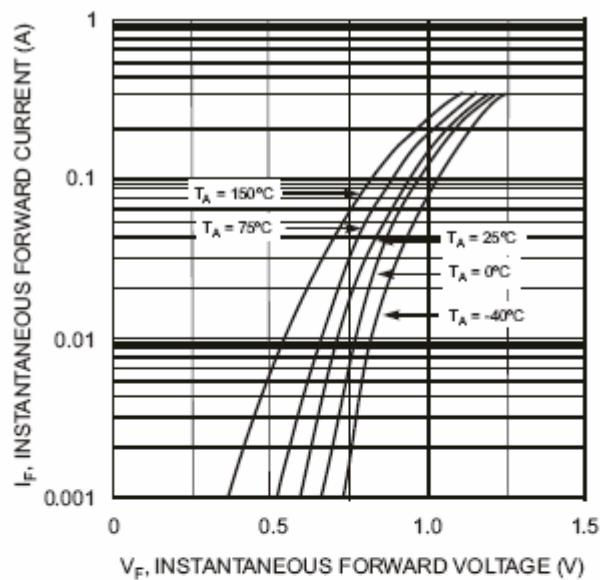


Fig. 2 Forward Characteristics

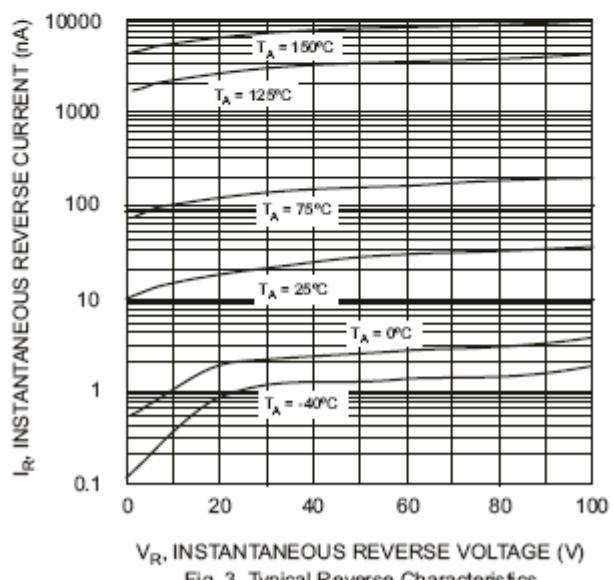


Fig. 3 Typical Reverse Characteristics

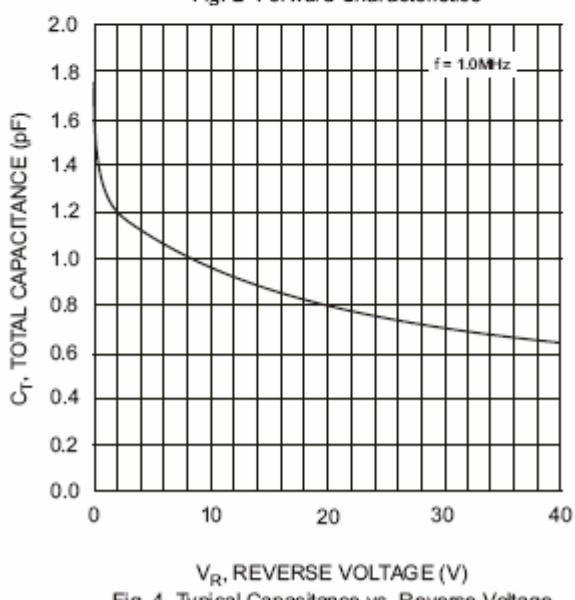


Fig. 4 Typical Capacitance vs. Reverse Voltage